
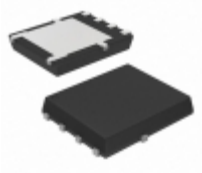
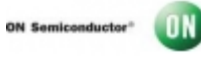
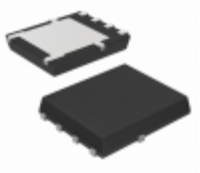
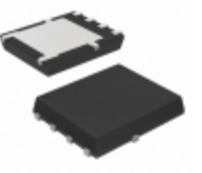

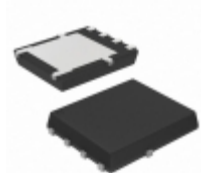

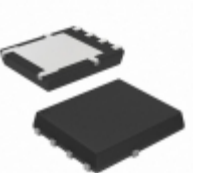
	<h2 style="color: red;">NTMFS4C09NAT1G</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">NTMFS4C09NAT1G</a></p> <p><b>Hersteller / Marke:</b> <a href="#">AMI Semiconductor / ON Semiconductor</a></p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 30V 9A SO8FL</p> <p><b>Datenblätter:</b>  <a href="#">NTMFS4C09NAT1G.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS nicht konform</p> <p><b>Lagerzustand:</b> New original, 1985 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">NTMFS4C09NAT1G</a>
Hersteller	<a href="#">AMI Semiconductor / ON Semiconductor</a>
Beschreibung	MOSFET N-CH 30V 9A SO8FL
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	1985 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-PowerTDFN, 5 Leads
Supplier Device-Gehäuse	5-DFN (5x6) (8-SOFL)
Verlustleistung (max)	760mW (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	9A (Ta), 52A (Tc)
Rds On (Max) @ Id, Vgs	5.8 mOhm @ 30A, 10V
VGS (th) (Max) @ Id	2.1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	1.9nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	1252pF @ 15V
Verpackung	Tape & Reel (TR)

NTMFS4C09NAT1G ist neu im Original. Suche NTMFS4C09NAT1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTMFS4C09NAT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTMFS4C09NAT1G: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>NTMFS4C09NT1G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 9A SO8FL</p>	 <p><b>NTMFS4C09NBT3G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V SO8FL</p>	 <p><b>NTMFS4C08NT1G-001</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 9A SO8FL</p>	 <p><b>NTMFS4C06NT3G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 69A SO8FL</p>
 <p><b>NTMFS4C09NBT1G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V SO8FL</p>	 <p><b>NTMFS4C09NT1G-001</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 9A SO8FL</p>	 <p><b>NTMFS4C08NAT1G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 16.4A 52A 5DFN</p>	 <p><b>NTMFS4C08NT3G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 52A SO8FL</p>

### heiße Teile

Mehr

NTMFS4933NT1G	NTMFS4934NT1G	NTMFS4935N	NTMFS4935NT1G	NTMFS4936N
NTMFS4936NT1G	NTMFS4937N	NTMFS4937NT1G	NTMFS4939NT1G	NTMFS4939NT3G
NTMFS4941NT1G	NTMFS4943NT1G	NTMFS4945NT1G	NTMFS4946N	NTMFS4946NT1G
NTMFS4955NT1G	NTMFS4982NFT1G	NTMFS4983NBFTG	NTMFS4983NFT1G	NTMFS4985NFT1G
NTMFS4C05N	NTMFS4C05NT1G	NTMFS4C06N	NTMFS4C06NT1G	NTMFS4C08NT1G
NTMFS4C09NT1G	NTMFS4C10NT1G	NTMFS4C13NT1G	NTMFS4C35N	NTMFS4C55NT1G
NTMFS4C58NT1G	NTMFS4C800NT1G	NTMFS5844NLT1G	NTMFS5C404NLT1G	NTMFS5C612NLT1G
NTMFS5C628NLT1G	NTMFS5C646NLT1G	NTMFS5C670NLT1G	NTMS10P02	NTMS10P02R2
NTMS10P02R2G	NTMS3P03R2	NTMS3P03R2G	NTMS4101PR2G	NTMS4105NR2G
NTMS4107NR2G	NTMS4176PR2G	NTMS4177P	NTMS4177PR2G	NTMS4404NR2G

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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